

MC78MXX/LM78MXX

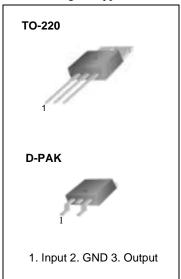
3-Terminal 0.5A Positive Voltage Regulator

Features

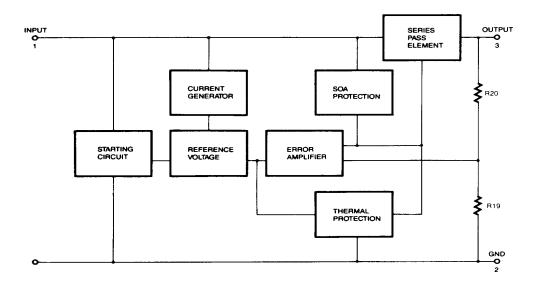
- Output Current up to 0.5A
- Output Voltages of 5, 6, 8, 10, 12, 15, 18, 20, 24V
- · Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe Operating Area (SOA)Protection

Description

The MC78MXX/LM78MXX series of three-terminal positive regulators are available in the TO-220/D-PAK package with several fixed output voltages making it useful in a wide range of applications.



Internal Block Digram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for V _O = 5V to 18V) (for V _O = 20V to 24V)	V _I V _I	35 40	V V
Thermal Resistance Junction-Cases (TO-220)	R _θ JC	5	°C/W
Thermal Resistance Junction-Air (TO-220 Package)	RθJA	65	°C/W
Operating Temperature Range MC78MXX/LM78MXX	TOPR	0~ + 125	°C
Storage Temperature Range	TSTG	-65~ + 150	°C

Electrical Characteristics (MC78M05/LM78M05)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, $I_O=350mA$, $V_I=10V$, unless otherwise specified, $C_I=0.33\mu F$, $C_O=0.1\mu F$)

Parameter	Symbol	Con	ditions	Min.	Тур.	Max.	Unit		
		TJ=+25°C		TJ=+25°C		4.8	5	5.2	
Output Voltage	Vo	IO = 5mA to 35 V _I = 7V to 20V	0mA	4.75	5	5.25	V		
Line Regulation (Note1)	ΔVο	I _O = 200mA	V _I = 7V to 25V	-	-	100	mV		
Line Regulation (Note1)	ΔνΟ	TJ =+25°C	V _I = 8V to 25V	-	-	50	IIIV		
Load Degulation (Nata1)	4)/0	IO = 5mA to 0.5	5A, TJ =+25°C	-	-	100	mV		
Load Regulation (Note1)	ΔVO	IO = 5mA to 20	0mA, TJ =+25 °C	-	-	50	IIIV		
Quiescent Current	IQ	T _{J=+25°} C		-	4.0	6.0	mA		
		IO = 5mA to 35	0mA	-	-	0.5			
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 8V to 25V		-	-	0.8	mA		
Output Voltage Drift	ΔV/ΔΤ	I _O = 5mA T _J = 0 to +125°	°C	-	-0.5	-	mV/°C		
Output Noise Voltage	VN	f = 10Hz to 100)KHz	-	40	-	μV/Vo		
Ripple Rejection	RR	f = 120Hz, IO = 300mA VI = 8V to 18V		62	-	-	dB		
Dropout Voltage	VD	TJ =+25°C, IO = 500mA		-	2	-	V		
Short Circuit Current	Isc	TJ=+25°C, VI= 35V		-	300	-	mA		
Peak Current	IPK	TJ =+25°C		-	700	-	mA		

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M06)

(Refer to the test circuits, $0 \le TJ \le +125$ °C, IO=350mA, VI =11V, unless otherwise specified, CI=0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		TJ=+25°C	TJ=+25°C		6	6.25	
Output Voltage	Vo	IO = 5mA to 3 V _I = 8V to 21\		5.7	6	6.3	V
Line Regulation (Note1)	ΔVο	Io = 200mA	VI= 8V to 25V	-	-	100	mV
Line Regulation (Note I)	ΔνΟ	TJ =+25°C	V _I = 9V to 25V	-	-	50	IIIV
Load Regulation (Note1)	ΔVο	IO = 5mA to 0).5A, TJ =+25°C	-	-	120	mV
Load Regulation (Note1)	ΔνΟ	$I_O = 5mA \text{ to } 2$	200mA, TJ =+25°C	-	-	60	IIIV
Quiescent Current	IQ	TJ=+25°C		-	4.0	6.0	mA
		$I_O = 5mA \text{ to } 3$	350mA	-	-	0.5	
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 9V to 25	V	-	-	0.8	mA
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +12	5°C	-	- 0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 10	00KHz	-	45	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 300mA VI = 9V to 19V		59	-	-	dB
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V
Short Circuit Current	Isc	TJ= +25°C, V	'i= 35V	-	300	-	mA
Peak Current	IPK	TJ =+25°C		-	700	-	mA

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M08)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, $I_O=350mA$, $V_I=14V$, unless otherwise specified, $C_I=0.33\mu F$, $C_O=0.1\mu F$)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _{J=+25} °C	TJ=+25 °C		8	8.3	
Output Voltage	Vo	IO = 5mA to 350 V _I = 10.5V to 23		7.6	8	8.4	V
Line Regulation (Note1)	ΔVο	Io = 200mA	V _I = 10.5V to 25V	-	-	100	mV
Line Regulation (Note I)	ΔνΟ	TJ =+25°C	V _I = 11V to 25V	-	-	50	IIIV
Load Regulation (Note1)	ΔVο	IO = 5mA to 0.5	A, TJ =+25°C	-	-	160	m\/
Load Regulation (Note1)	ΔνΟ	Io = 5mA to 200	OmA, TJ =+25°C	-	-	80	mV
Quiescent Current	IQ	TJ=+25°C		-	4.0	6.0	mA
		IO = 5mA to 350mA		-	-	0.5	
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 10.5V to 28	5V	-	-	0.8	mA
Output Voltage Drift	RR	IO = 5mA T _J = 0 to +125°	С	-	-0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100	KHz	-	52	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 11.5V to 21.5V		56	-	-	dB
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V
Short Circuit Current	Isc	TJ =+25°C, VI= 35V		-	300	-	mA
Peak Current	IPK	TJ =+25°C		-	700	-	mA

Load and line regulation are specified at constant junction temperature. Change in V₀ due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M10)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, IO=350mA, VI=14V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
		TJ= +25°C	T _J = +25°C		10	10.4	
Output Voltage	Vo	IO = 5mA to 3 V _I = 12.5V to 2		9.5	10	10.5	V
Line Regulation (Note1)	۸۷/۵	Io = 200mA	V _I = 12.5V to 25V	-	-	100	mV
Line Regulation (Note I)	ΔVο	TJ =+25°C	V _I = 13V to 25V	-	-	50	IIIV
Load Population (Note1)	۸۷/۵	IO = 5mA to 0	0.5A, TJ =+25°C	-	-	200	mV
Load Regulation (Note1)	ΔVO	I _O = 5mA to 2	200mA, TJ =+25°C	-	-	100	IIIV
Quiescent Current	lQ	TJ=+25°C		-	4.1	6.0	mA
	IO = 5mA to 350mA		-	-	0.5		
Quiescent Current Change	ΔlQ	IO = 200mA VI = 12.5V to	25V	-	-	0.8	mA
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +125	5°C	-	-0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 10	00KHz	-	65	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 13V to 23V		55	-	-	dB
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V
Short Circuit Current	Isc	TJ= +25°C, VI= 35V		-	300	-	mA
Peak Current	IPK	TJ =+25°C		-	700	-	mA

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M12)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, IO=350mA, VI=19V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit		
		T _J =+25°C		T _J =+25°C		11.5	12	12.5	
Output Voltage	Vo	IO = 5mA to 35 V _I = 14.5V to 27	-	11.5	12	12.6	V		
Line Regulation (Note1)	4\/0	IO = 200mA	V _I = 14.5V to 30V	-	-	100	mV		
Line Regulation (Note1)	ΔVΟ	TJ =+25°C	V _I = 16V to 30V	-	-	50] ''''		
Load Population (Note1)	ΔVο	IO = 5mA to 0.5	5A, TJ =+25°C	-	-	240	m\/		
Load Regulation (Note1)	ΔνΟ	I _O = 5mA to 20	0mA, T _J =+25°C	-	-	120	mV		
Quiescent Current	IQ	TJ=+25°C		-	4.1	6.0	mA		
		I _O = 5mA to 35	0mA	-	-	0.5			
Quiescent Current Change	ΔIQ	I _O = 200mA V _I = 14.5V to 3	0V	-	-	0.8	mA		
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +125°	С	-	- 0.5	-	mV/°C		
Output Noise Voltage	VN	f = 10Hz to 100	KHz	-	75	-	μV/Vo		
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 15V to 25V		55	-	-	dB		
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V		
Short Circuit Current	Isc	TJ= +25°C, VI= 35V		-	300	-	mA		
Peak Current	lpK	T _J = +25°C		-	700	-	mA		

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M15)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, IO=350mA, VI=23V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Co	nditions	Min.	Тур.	Max.	Unit
		T _J =+25°C	T _J =+25°C		15	15.6	
Output Voltage	Vo	IO = 5mA to 3 V _I = 17.5V to		14.25	15	15.75	V
Line Regulation (Note1)	ΔVο	IO = 200mA	V _I = 17.5V to 30V	-	-	100	mV
Line Regulation (Note I)	ΔνΟ	TJ =+25°C	V _I = 20V to 30V	-	-	50	IIIV
Load Population (Note1)	ΔVο	IO = 5mA to 0	0.5A, TJ =+25°C	-	-	300	mV
Load Regulation (Note1)	ΔνΟ	$I_O = 5mA \text{ to } 2$	200mA, TJ =+25°C	-	-	150	IIIV
Quiescent Current	IQ	TJ=+25°C		-	4.1	6.0	mA
		$I_O = 5mA to 3$	350mA	-	-	0.5	
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 17.5V to	30V	-	-	0.8	mA
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +12	5°C	-	– 1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 1	00KHz	-	100	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 18.5V to 28.5V		54	-	-	dB
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V
Short Circuit Current	Isc	TJ= +25°C, V = 35V		-	300	-	mA
Peak Current	IPK	T _J = + 25°C		-	700	-	mA

Load and line regulation are specified at constant junction temperature. Change in V₀ due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M18)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, IO=350mA, VI=26V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit	
		TJ=+25°C 1		T _J =+25°C		17.3	18	18.7
Output Voltage	Vo	_	IO = 5mA to 350mA V _I = 20.5V to 33V		18	18.9	V	
Line Regulation (Note1)	ΔVο	Io = 200mA	V _I = 21V to 33V	-	-	100	mV	
Line Regulation (Note I)	ΔνΟ	T _J =+25°C	V _I = 24V to 33V	-	-	50	IIIV	
Load Population (Note1)	ΔVΟ	IO = 5mA to 0.5	A, TJ =+25°C	-	-	360	mV	
Load Regulation (Note1)	ΔνΟ	I _O = 5mA to 200	OmA, TJ =+25°C	-	-	180	IIIV	
Quiescent Current	lQ	TJ =+25°C		-	4.2	6.0	mA	
		I _O = 5mA to 350	DmA	-	-	0.5		
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 21V to 33V	,	-	-	0.8	mA	
Output Voltage Drift	ΔV/ΔΤ	IO =5mATJ =0 t	o 125°C	-	-1.1	-	mV/°C	
Output Noise Voltage	VN	f=10Hz to 100K	Hz	-	100	-	μV/Vo	
Ripple Rejection	RR	f=120Hz, I _O =300mA , V _I =22V to 32V		53	-	-	dB	
Dropout Voltage	VD	T _J =+25°C, I _O =500mA		-	2	-	V	
Short Circuit Current	Isc	T _J =+25°C, V _I =35V		-	300	-	mA	
Peak Current	IPK	TJ =+25°C		-	700	-	mA	

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M20)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, IO=350mA, VI=29V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T _J = +25°C	T _J = +25°C		20	20.8	
Output Voltage	Vo	IO = 5mA to V _I = 23V to 3		19	20	21	V
Line Regulation (Note1)	ΔVο	IO = 200mA	V _I = 23V to 35V	-	-	100	mV
Line Regulation (Note I)	ΔνΟ	T _J =+25°C	V _I = 24V to 35V	-	-	50	IIIV
Load Population (Note1)	ΔVο	IO = 5mA to	0.5A, TJ =+25°C	-	-	400	mV
Load Regulation (Note1)	ΔνΟ	$I_O = 5mA to$	200mA, TJ =+25°C	-	-	200	IIIV
Quiescent Current	IQ	TJ=+25°C		-	4.2	6.0	mA
		IO = 5mA to	I _O = 5mA to 350mA		-	0.5	
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 23V to 3	35V	-	-	0.8	mA
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +12	25°C	-	-1.1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 1	00KHz	-	110	-	μV
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 24 to 34V		53	-	-	dB
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA		-	2	-	V
Short Circuit Current	Isc	TJ = +25°C, VI= 35V		-	300	-	mA
Peak Current	IPK	T _J = +25°C		-	700	-	mA

^{*}Load and line regulation are specified at constant junction temperature. Change in V₀ due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC78M24)

(Refer to the test circuits, $0 \le T_J \le +125^{\circ}C$, IO=350mA, VI=33V, unless otherwise specified, CI =0.33 μ F, CO=0.1 μ F)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
		T _J =+25°C		24	25	
Output Voltage	Vo	IO = 5mA to 350mA VI= 27V to 38V		24	25.2	V
Line Regulation (Note1)	4\/0	IO = 200mA VI= 27V to 38V	-	-	100	mV
Line Regulation (Note I)	ΔVO	$T_J = +25^{\circ}C$ $V_I = 28V \text{ to } 38V$	-	-	50	IIIV
Load Regulation (Nata1)	41/0	$IO = 5mA \text{ to } 0.5A, TJ = +25^{\circ}C$	-	-	480	mV
Load Regulation (Note1)	ΔVO	Io = 5mA to 200mA, T _J =+25°	С -	-	240	mv
Quiescent Current	IQ	TJ=+25°C	-	4.2	6.0	mA
		IO = 5mA to 350mA	-	-	0.5	
Quiescent Current Change	ΔlQ	I _O = 200mA V _I = 27V to 38V	-	-	0.8	mA
Output Voltage Drift	ΔV/ΔΤ	IO = 5mA T _J = 0 to +125°C	-	- 1.2	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100KHz	-	170	-	μV/Vo
Ripple Rejection	RR	f = 120Hz, I _O = 300mA V _I = 28V to 38V	50	-	-	dB
Dropout Voltage	VD	T _J =+25°C, I _O = 500mA	-	2	-	V
Short Circuit Current	Isc	TJ= +25 °C, VI= 35V	-	300	-	mA
Peak Current	IPK	T _J =+25°C	-	700	-	mA

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_0 due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Typical Applications

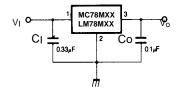


Figure 1. Fixed Output Regulator

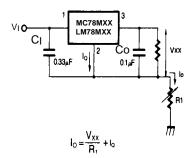


Figure 2. Constant Current Regulator

- 1. To specify an output voltage, substitute voltage value for "XX"
- 2. Although no output capacitor is needed for stability, it does improve transient response.
- 3. C_I is required if regulator is located an appreciable distance from power Supply filter

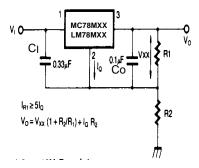


Figure 3. Circuit for Increasing Output Voltage

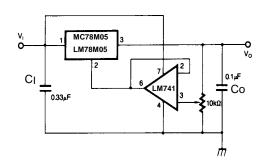


Figure 4. Adjustable Output Regulator (7 to 30V)

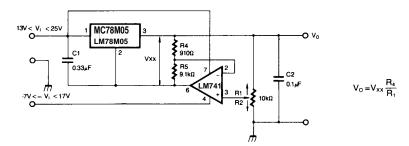
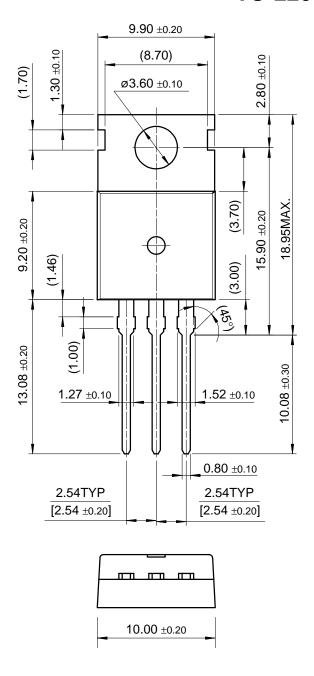


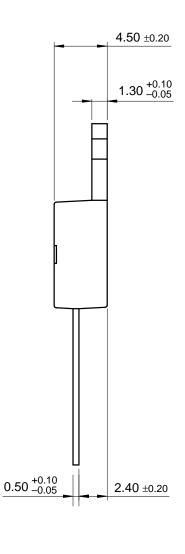
Figure 5. 0.5 to 10V Regulator

Mechanical Dimensions

Package

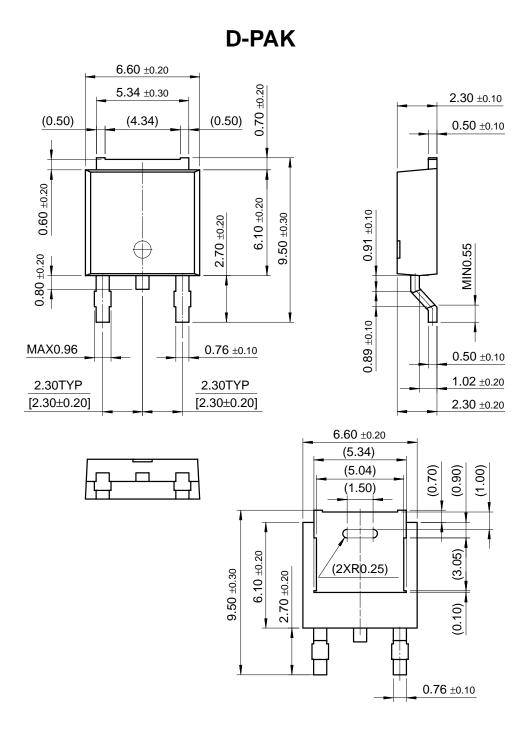
TO-220





Mechanical Dimensions (Continued)

Package



Ordering Information

Product Number	Package	Operating Temperature
LM78M05CT	TO-220	0 ~ + 125°C
Product Number	Package	Operating Temperature
MC78M05CT		
MC78M06CT		
MC78M08CT		
MC78M09CT		
MC78M10CT	TO-220	
MC78M12CT	10-220	
MC78M15CT		
MC78M18CT		0 ~ + 125°C
MC78M20CT		0~+125 C
MC78M24CT		
MC78M05CDT		
MC78M06CDT		
MC78M08CDT	D-PAK	
MC78M09CDT	D-PAK	
MC78M12CDT]	
MC78M08ADT		

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